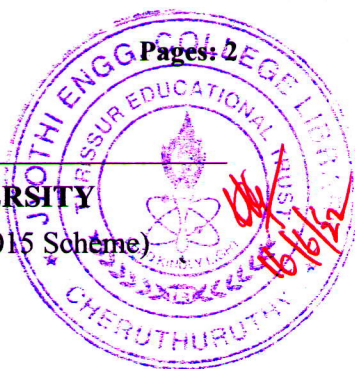


Reg No.: _____

Name: _____

APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

B.Tech Degree S1 (S,FE) S2 (S) Examination May 2022 (2015 Scheme)

**Course Code: BE101-04****Course Name: INTRODUCTION TO ELECTRONICS ENGINEERING**

Max. Marks: 100

Duration: 3 Hours

PART A*Answer all questions, each carries 5 marks*

Marks

- | | | |
|---|---|-----|
| 1 | List the applications of Electronics in industry and explain any one of them. | (5) |
| 2 | Describe the working of a solar cell. Give its application. | (5) |
| 3 | Explain the structure and typical doping of a bipolar junction transistor. | (5) |
| 4 | Compare and contrast JFET with BJT. | (5) |
| 5 | Explain the components of a regulated power supply. | (5) |
| 6 | Draw the circuit of a positive clamping circuit and explain its working. | (5) |
| 7 | With a block diagram explain the working of a DSO. | (5) |
| 8 | Define any two performance parameters of an electronic instrument. | (5) |

PART B*Answer six questions, one full question from each module and carries 10 marks.***MODULE I**

- | | | |
|---|---|-----|
| 9 | a) Explain the construction of wire wound resistors. | (5) |
| | b) State the function of an inductor. Which are the various types of inductors? | (5) |

OR

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|----|--|-----|
| 10 | a) Describe the principle of operation of a solid-state relay and compare it with electromechanical relay. | (5) |
| | b) Explain the construction of carbon film resistors. | (5) |

MODULE II

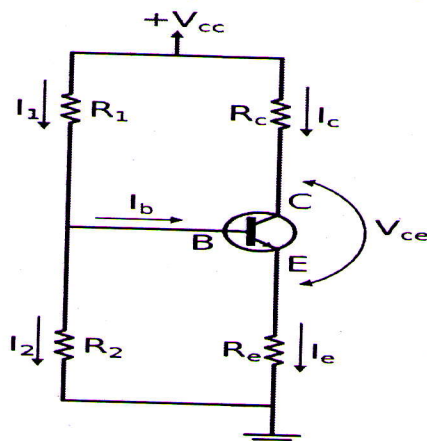
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|----|--|------|
| 11 | Draw the V-I characteristics of a PN junction diode and explain how barrier potential is generated in a PN junction. | (10) |
|----|--|------|

OR

- | | | |
|----|--|------|
| 12 | Differentiate between intrinsic and extrinsic semiconductors. Explain the formation of N-type semiconductor. | (10) |
|----|--|------|

MODULE III

- 13 a Explain the need for biasing a BJT. (2)
- b Find the values of resistances R_1 , R_2 , R_c , R_e for a voltage divider biasing circuit. Given $V_{cc}=10V$, $I_c=1mA$, $\beta=100$ and $V_{CE}=50\%$ of V_{cc} (8)



OR

- 14 Draw and explain the circuit diagram and frequency response of an RC coupled amplifier. (10)

MODULE IV

- 15 With neat sketches explain the working and drain characteristics of an N-channel JFET. (10)

OR

- 16 a Describe the working of an Enhancement type MOSFET. (6)
- b Explain the working of a phototransistor. List its applications (4)

MODULE V

- 17 Draw the circuit and explain the working of a centre tap full wave rectifier. Derive the I_{rms} , I_{dc} and ripple factor of a centre tap full wave rectifier. (10)

OR

- 18 Explain the working of a slicer circuit. Draw a circuit to clip a given $10V_{pp}$ sine wave at $+3V$ and $-2V$. Also draw the input and output waveforms. (10)

MODULE VI

- 19 Explain the working of an analog multimeter and describe how it can be used for measuring resistance and voltage. (10)

OR

- 20 a) What are Lissajous patterns? How frequency and phase difference be measured with Lissajous patterns? (5)
- b) Explain the working of a function generator. (5)
